

L Number	Hits	Search Text	DB	Time stamp
1	513361	semiconductor and (tft or (thin film transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/29 13:51
2	7977	(semiconductor and (tft or (thin film transistor))) and gate and drain and source and offset	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/29 13:52
3	1075	((semiconductor and (tft or (thin film transistor))) and gate and drain and source and offset) and sidewall	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/29 13:52
4	1075	((((semiconductor and (tft or (thin film transistor))) and gate and drain and source and offset) and sidewall) and (gate electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/29 13:53
5	1075	(((((semiconductor and (tft or (thin film transistor))) and gate and drain and source and offset) and sidewall) and (gate electrode)) and (offset region)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/29 13:54
6	948	((((((semiconductor and (tft or (thin film transistor))) and gate and drain and source and offset) and sidewall) and (gate electrode)) and (offset region)) and (thin film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/29 13:58
7	5129	(257/57, 59, 66, 72, 347, 350, 329, 330, "331").ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/29 13:59